描述

TO-252 N

N-CHANNEL MOSFET in a TO-252 Plastic Package.

特征

$R_{DS(on)}$ C_{rss} AEC-Q101

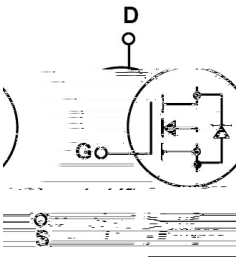
Low $R_{DS(on)}$,low gate charge, low C_{rss}, fast switching, Qualified to AEC-Q101 Standards for High Reliability, HF Product.

用途

DC/DC

Suited for low voltage applications such as automotive, DC/DC Converters, and high efficiency switching for power management in portable and battery operated products, Meet the stringent requirements of automotive applications.

内部等效电



脚排列

PIN1 G PIN 2 D PIN 3 S PIN 4 D

印章代码

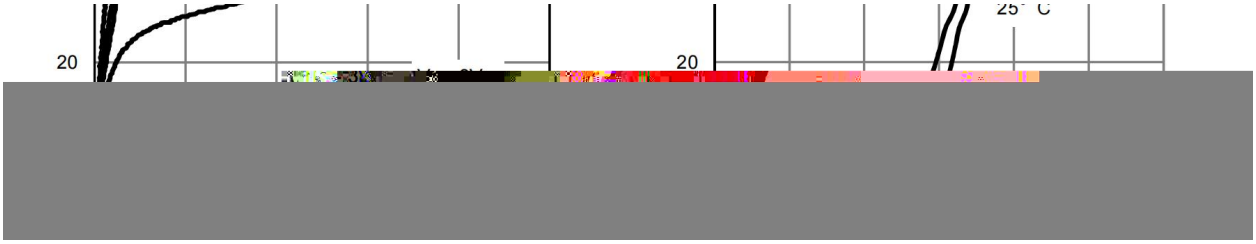
See Marking Instructions.

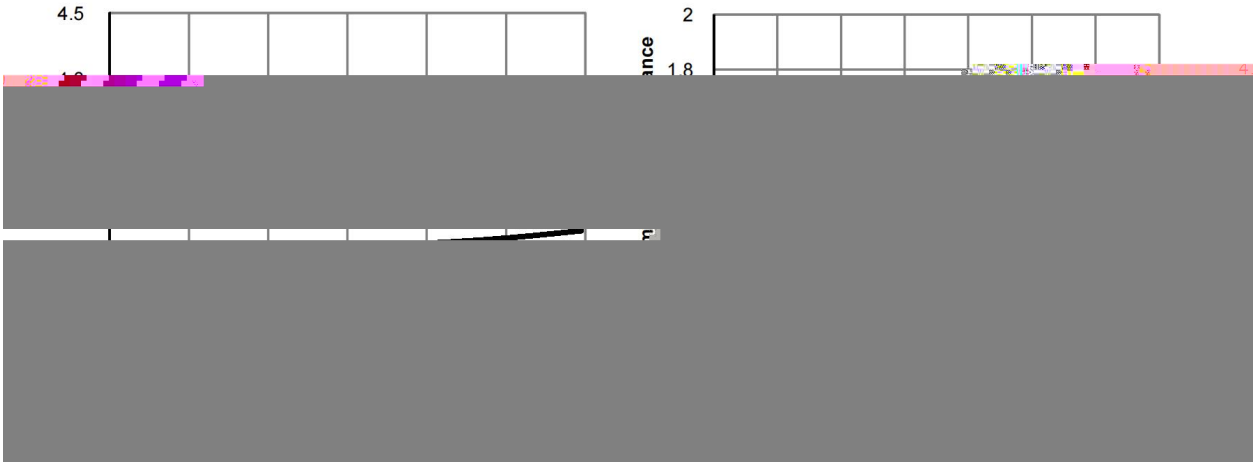
Parameter	Symbol	Rating	Unit

电

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Turn-On Delay Time	$t_{d(on)}$	V_{GS}=10V V_{DS}=30V R_L=1.5Ω R_{GEN}=3Ω		13		ns
Turn-On Rise Time	t_r			4		
Turn-Off Delay Time	$t_{d(off)}$			47		
Turn-Off Fall Time	t_f			6.5		

电





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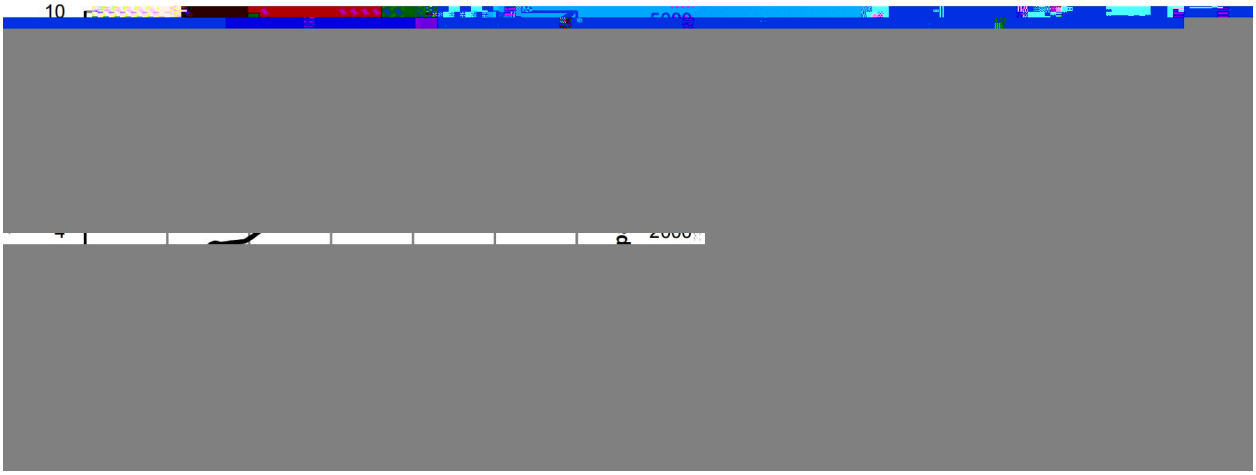

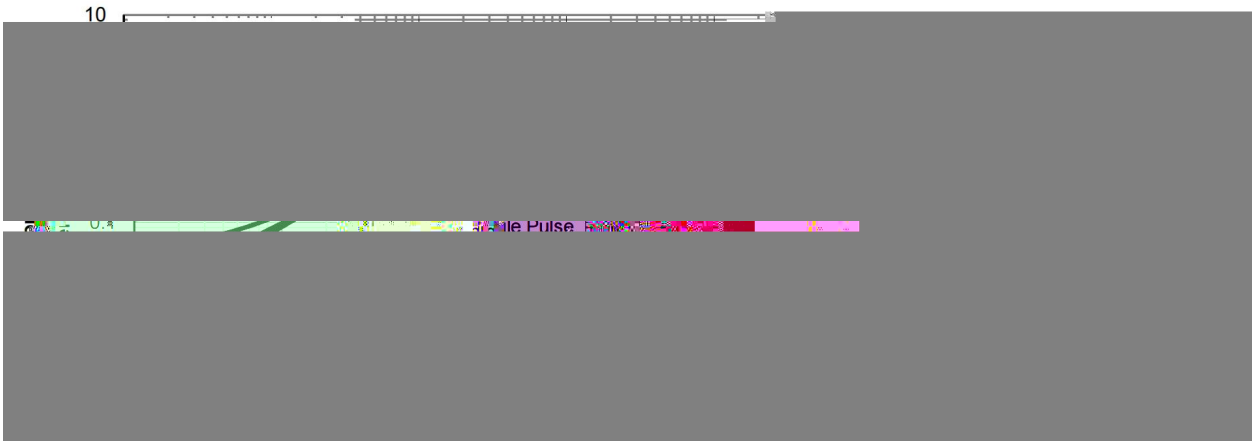

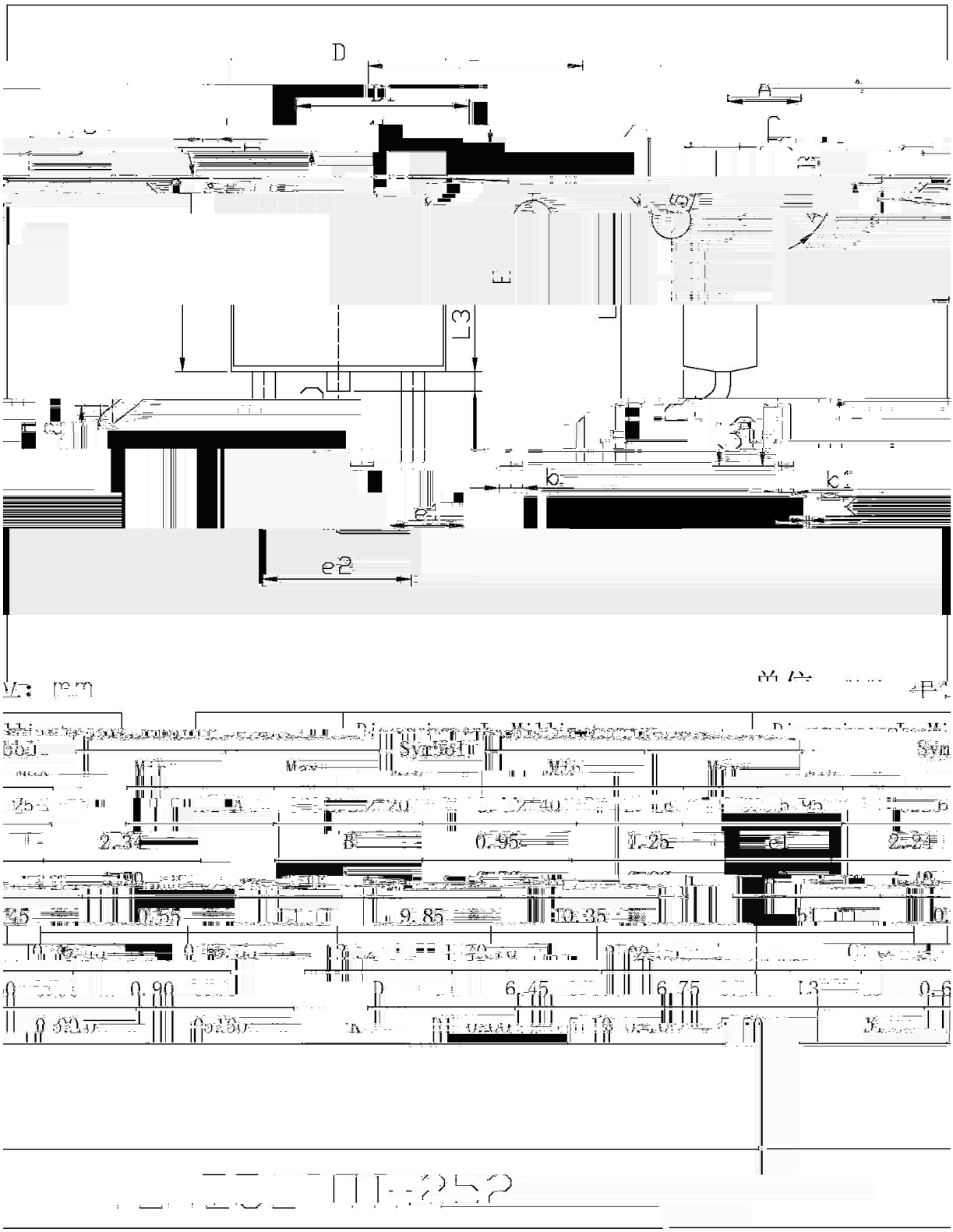
D
L3
e2
Symbol
2.34
0.95
1.25
2.24
0.55
9.85
10.35
0.90
6.45
6.75

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Note:

1	150	200	60	120sec;	1.Preheating:150~200 , Time:60~120sec.
2	255±5			5±0.5sec;	2.Peak Temp.:255±5 , Duration:5±0.5sec.
3		2	10	/sec.	3. Cooling Speed: 2~10 /sec.

260±5 10±1 sec. Temp.:260±5℃ Time:10±1 sec

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm^3)		
	Units/Reel /	Reels/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Reel	Inner Box 盒	Outer Box 箱
TO-252	2,500	2	5,000	6	30,000	13″ ×16	360×360×50	380×335×366